

Standard Rectifier

$$V_{RRM} = 2 \times 1600 \text{ V}$$

$$I_{FAV} = 30 \text{ A}$$

$$V_F = 1.2 \text{ V}$$

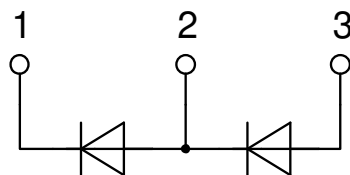
Phase leg

Part number

DMA30P1600HB



Backside: anode/cathode



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour
- High commutation robustness
- High surge capability

Applications:

- Diode for main rectification
- For single and three phase bridge configurations

Package: TO-247

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

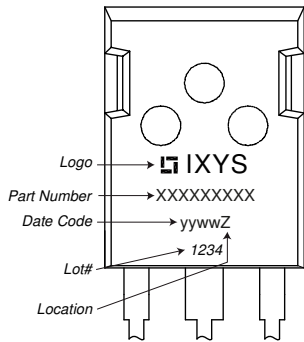
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Rectifier				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
V_{RSM}	max. non-repetitive reverse blocking voltage				1700	V	
V_{RRM}	max. repetitive reverse blocking voltage				1600	V	
I_R	reverse current	$V_R = 1600$ V			40	μ A	
		$V_R = 1600$ V			1.5	mA	
V_F	forward voltage drop	$I_F = 30$ A			1.26	V	
		$I_F = 60$ A			1.53	V	
		$I_F = 30$ A			1.20	V	
		$I_F = 60$ A			1.57	V	
I_{FAV}	average forward current	$T_C = 130^\circ$ C			30	A	
		180° sine					
V_{FO}	threshold voltage	} for power loss calculation only			0.81	V	
r_F	slope resistance				12.7	m Ω	
R_{thJC}	thermal resistance junction to case				0.8	K/W	
R_{thCH}	thermal resistance case to heatsink			0.3		K/W	
P_{tot}	total power dissipation				185	W	
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine			370	A	
		t = 8,3 ms; (60 Hz), sine			400	A	
		t = 10 ms; (50 Hz), sine			315	A	
		t = 8,3 ms; (60 Hz), sine			340	A	
I^2t	value for fusing	t = 10 ms; (50 Hz), sine			685	A ² s	
		t = 8,3 ms; (60 Hz), sine			665	A ² s	
		t = 10 ms; (50 Hz), sine			495	A ² s	
		t = 8,3 ms; (60 Hz), sine			480	A ² s	
C_J	junction capacitance	$V_R = 400$ V; f = 1 MHz			11	pF	



Package TO-247			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			70	A
T_{VJ}	virtual junction temperature		-55		175	°C
T_{op}	operation temperature		-55		150	°C
T_{stg}	storage temperature		-55		150	°C
Weight				6		g
M_D	mounting torque		0.8		1.2	Nm
F_C	mounting force with clip		20		120	N

Product Marking



Part description

- D = Diode
- M = Standard Rectifier
- A = (up to 1800V)
- 30 = Current Rating [A]
- P = Phase leg
- 1600 = Reverse Voltage [V]
- HB = TO-247AD (3)

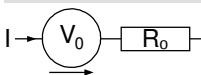
Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DMA30P1600HB	DMA30P1600HB	Tube	30	522379

Similar Part	Package	Voltage class
DMA30P1200HB	TO-247AD (3)	1200

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 175^{\circ}C$

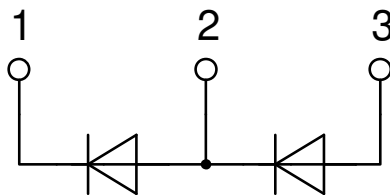


Rectifier

$V_{0\ max}$	threshold voltage	0.81	V
$R_{0\ max}$	slope resistance *	10.1	mΩ



Outlines TO-247



Rectifier

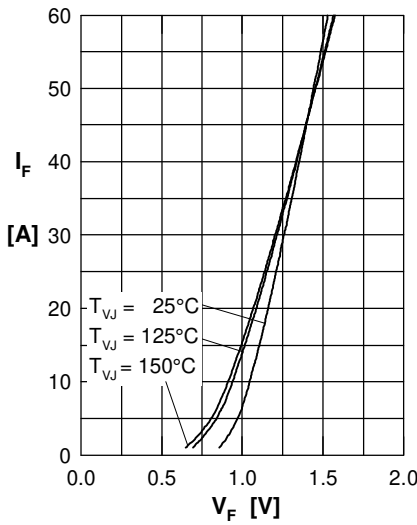


Fig. 1 Forward current versus voltage drop per diode

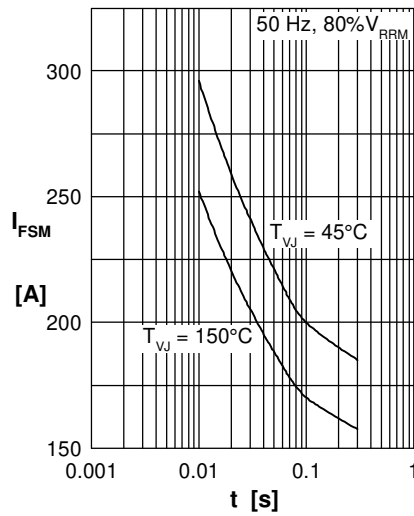


Fig. 2 Surge overload current versus time per diode

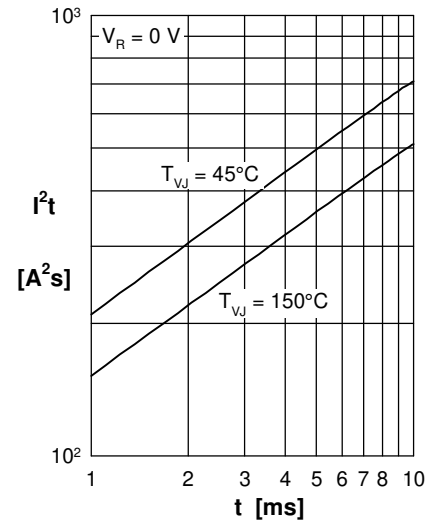


Fig. 3 I^2t versus time per diode

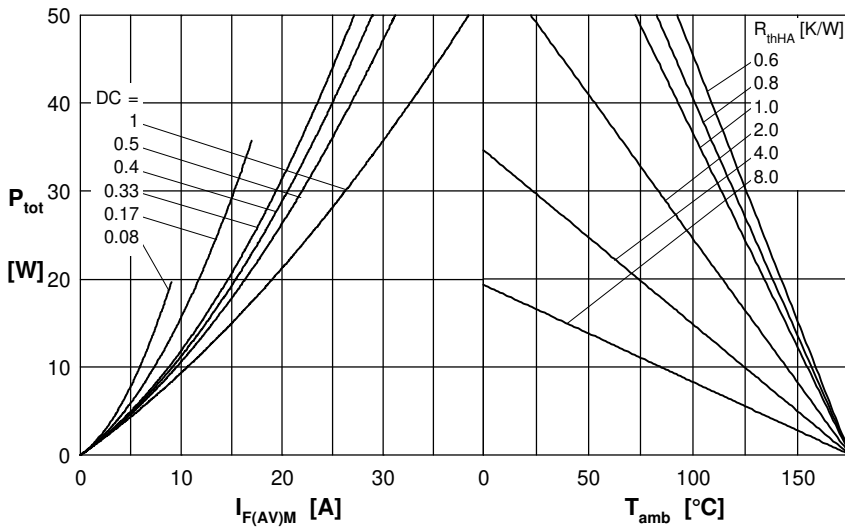


Fig. 4 Power dissipation versus direct output current and ambient temperature per diode

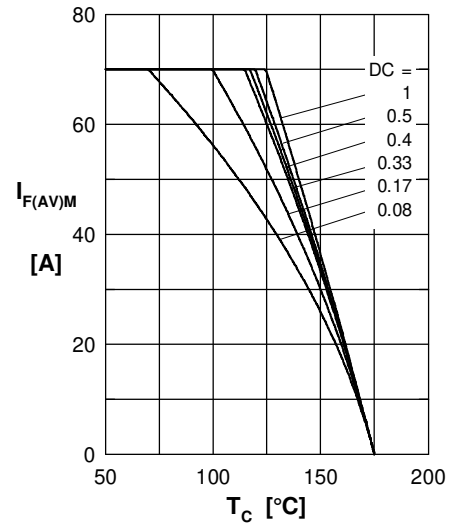


Fig. 5 Max. forward current versus case temperature per diode

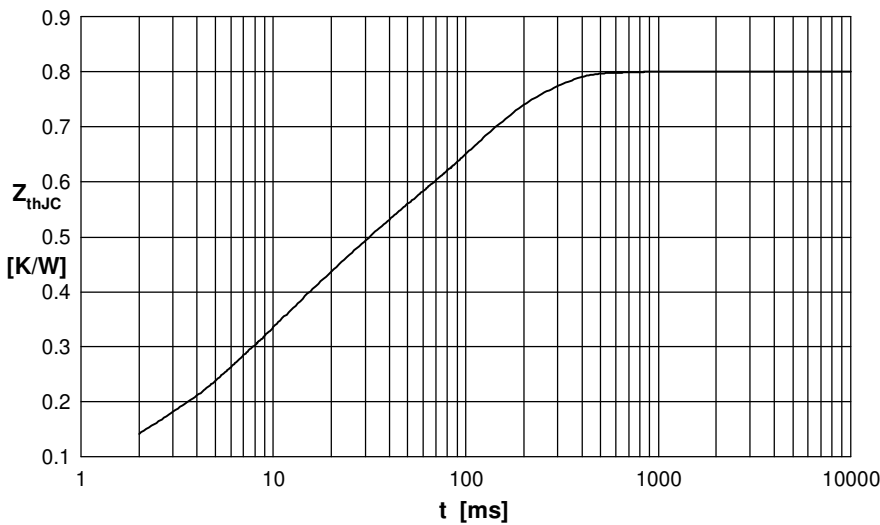


Fig. 6 Transient thermal impedance junction to case versus time per diode

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.05	0.0006
2	0.13	0.0040
3	0.25	0.0130
4	0.37	0.1100